NSN 5961-01-155-7829

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal
Overall Length:
Between 0.874 inches and 1.030 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.031 inches and 1.068 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1200.0 repetitive peak reverse voltage, peak total value
Current Rating Per Characteristic:
1.20 amperes source cutoff current peak
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pn
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 banana plug and 2 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fila:

A110a0